



PSMN8R5-40MSD

N-channel 40 V, 8.5 m Ω , standard level MOSFET in LFAK33 using NextPower-S3 technology

10 February 2020

Product data sheet

1. General description

60 A, standard level N-channel enhancement mode MOSFET in 175 °C LFAK33 package using advanced TrenchMOS Superjunction technology. This product has been designed and qualified for high efficiency applications at high switching frequencies.

2. Features and benefits

- Avalanche rated, 100% tested
- NextPower-S3 technology delivers 'superfast switching with soft body-diode recovery'
- Low Q_{RR} , Q_G and Q_{GD} for high system efficiency, especially at high switching frequencies
- Low spiking and ringing for low EMI designs
- High reliability clip bonded and solder die attach Mini Power SO8 package; no glue, no wire bonds, qualified to 175 °C
- Exposed leads can be wave soldered, visual solder joint inspection and high quality solder joints
- Low parasitic inductance and resistance

3. Applications

- Secondary side synchronous rectification
- DC-to-DC converters
- Brushless DC motor drive
- LED lighting

4. Quick reference data

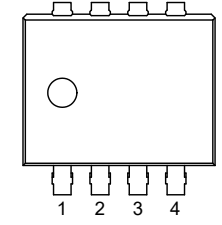
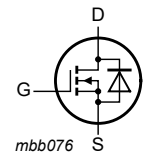
Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|---|-----|------|-----|------------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$ | - | - | 40 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}$; $T_{mb} = 25\text{ °C}$; Fig. 2 | [1] | - | 60 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 1 | - | - | 59 | W |
| T_j | junction temperature | | -55 | - | 175 | °C |
| Static characteristics | | | | | | |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10\text{ V}$; $I_D = 15\text{ A}$; $T_j = 25\text{ °C}$; Fig. 10 | - | 7.4 | 8.5 | m Ω |
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $I_D = 15\text{ A}$; $V_{DS} = 20\text{ V}$; $V_{GS} = 10\text{ V}$; Fig. 12 ; Fig. 13 | 0.6 | 2 | 4 | nC |
| $Q_{G(tot)}$ | total gate charge | | 9 | 13.4 | 19 | nC |

[1] 60A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|---|---|
| 1 | S | source |  <p>LPAK33 (SOT1210)</p> |  |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | Mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|---------------|---------|--|---------|
| | Name | Description | Version |
| PSMN8R5-40MSD | LPAK33 | Plastic, single ended surface mounted package (LPAK33); 8 leads; 0.65 mm pitch | SOT1210 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|---------------|--------------|
| PSMN8R5-40MSD | 8D5S40 |

8. Limiting values

Table 5. Limiting values

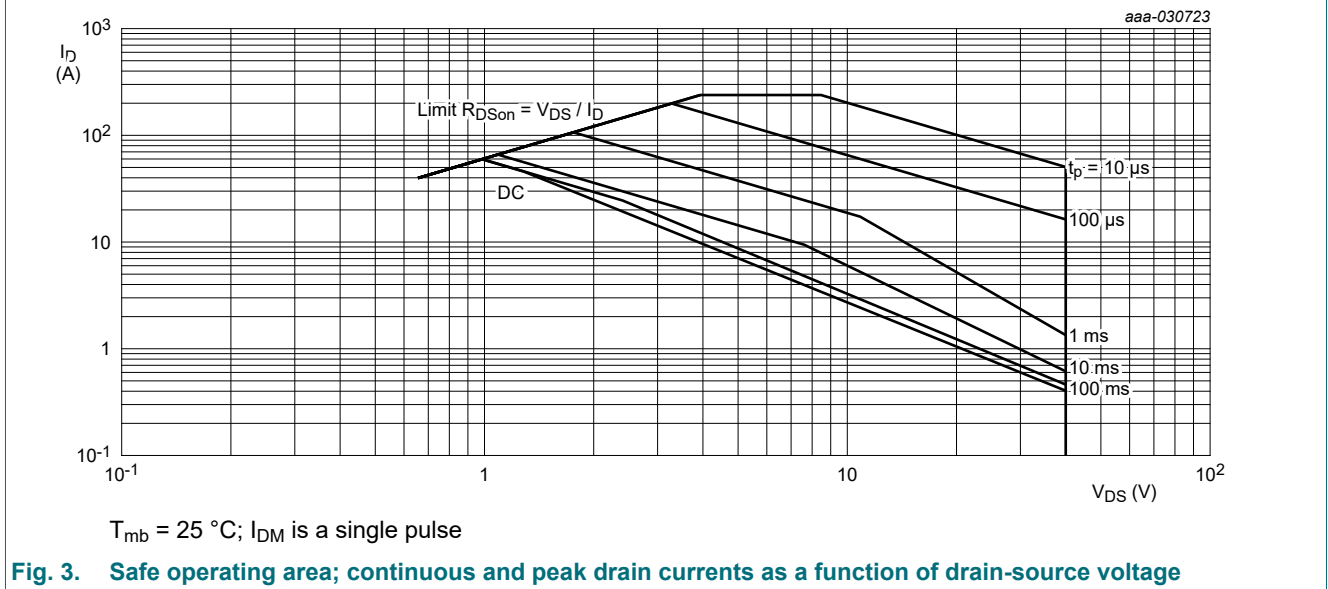
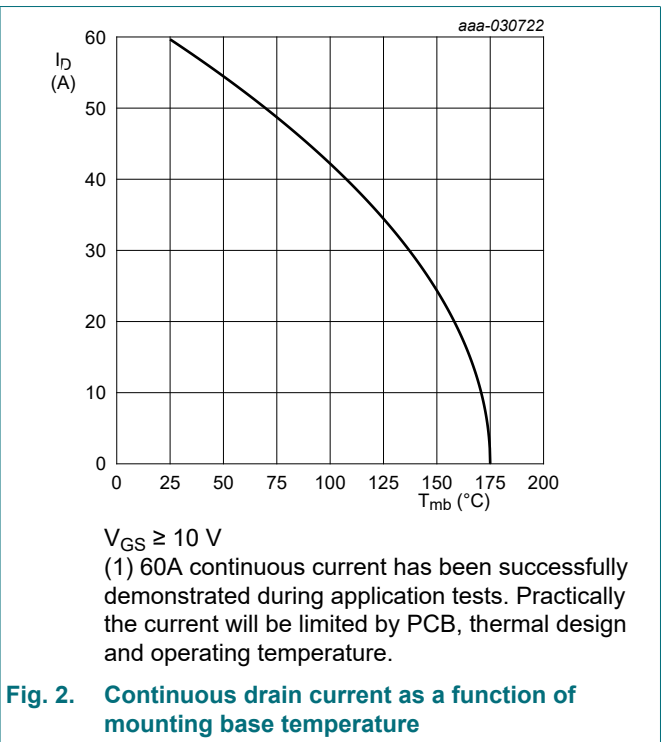
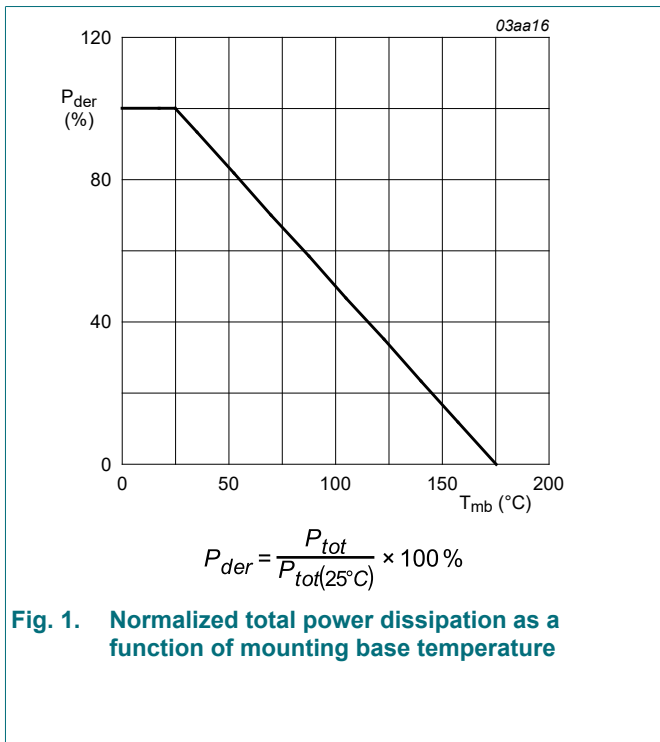
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------|----------------------------|--|-----|-----|------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$ | - | 40 | V |
| V_{DSM} | peak drain-source voltage | $t_p \leq 20\text{ ns}$; $f \leq 500\text{ kHz}$; $E_{DS(AL)} \leq 200\text{ nJ}$; pulsed | - | 45 | V |
| V_{DGR} | drain-gate voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$ | - | 40 | V |
| V_{GS} | gate-source voltage | | -20 | 20 | V |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 1 | - | 59 | W |
| I_D | drain current | $V_{GS} = 10\text{ V}$; $T_{mb} = 25\text{ °C}$; Fig. 2 | [1] | 60 | A |
| | | $V_{GS} = 10\text{ V}$; $T_{mb} = 100\text{ °C}$; Fig. 2 | - | 42 | A |
| I_{DM} | peak drain current | pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25\text{ °C}$; Fig. 3 | - | 239 | A |
| T_{stg} | storage temperature | | -55 | 175 | °C |
| T_j | junction temperature | | -55 | 175 | °C |
| $T_{sld(M)}$ | peak soldering temperature | | - | 260 | °C |
| Source-drain diode | | | | | |
| I_S | source current | $T_{mb} = 25\text{ °C}$ | - | 59 | A |

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| Symbol | Parameter | Conditions | Min | Max | Unit | |
|-----------------------------|--|---|-----|-----|------|----|
| I_{SM} | peak source current | pulsed; $t_p \leq 10 \mu s$; $T_{mb} = 25^\circ C$ | - | 239 | A | |
| Avalanche ruggedness | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $I_D = 22 A$; $V_{sup} \leq 40 V$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 V$; $T_{j(init)} = 25^\circ C$; unclamped; $t_p = 80 \mu s$ | [2] | - | 46 | mJ |
| | | $I_D = 15 A$; $V_{sup} \leq 40 V$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 V$; $T_{j(init)} = 25^\circ C$; unclamped; $t_p = 180 \mu s$ | [2] | - | 70 | mJ |

- [1] 60A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.
- [2] Protected by 100% test



9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------|-----|------|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 4 | - | 2.33 | 2.56 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | Fig. 5 | - | 50 | - | K/W |
| | | Fig. 6 | - | 130 | - | K/W |

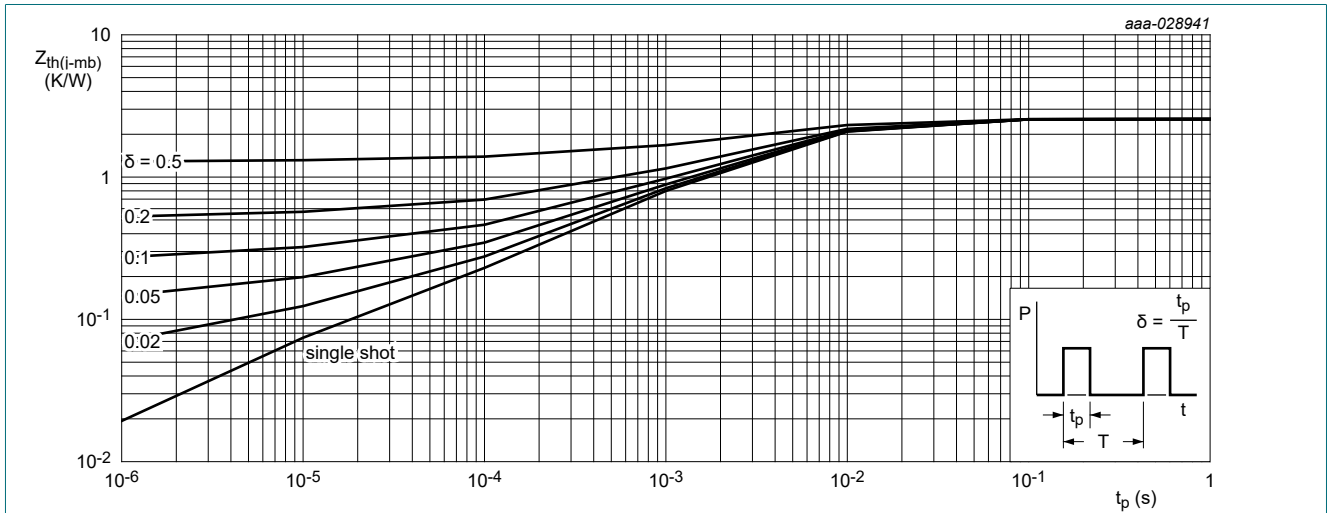


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

Copper area 25.4 mm x 25.4 mm; 70 μm thick on FR4 board

70 μm thick copper on FR4 board

Fig. 5. PCB layout for thermal resistance from junction to ambient

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------------|---|-----|-----|-----|------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 40 | - | - | V |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 36 | - | - | V |

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| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------------------------|--|---|-----|------|------|---------------|----|
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ\text{C}$ | 2.4 | 3.12 | 3.6 | V | |
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | $25 \text{ }^\circ\text{C} \leq T_j \leq 150 \text{ }^\circ\text{C}$ | - | -5.9 | - | mV/K | |
| I_{DSS} | drain leakage current | $V_{DS} = 32 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ | - | 0.01 | 1 | μA | |
| | | $V_{DS} = 32 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ }^\circ\text{C}$ | - | 1 | - | μA | |
| I_{GSS} | gate leakage current | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ | - | 2 | 100 | nA | |
| | | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ | - | 2 | 100 | nA | |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 10 | - | 7.4 | 8.5 | mΩ | |
| | | $V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 175 \text{ }^\circ\text{C};$ Fig. 11 | - | - | 16.5 | mΩ | |
| R_G | gate resistance | $f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}$ | 0.3 | 0.8 | 2 | Ω | |
| Dynamic characteristics | | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 15 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 12; Fig. 13 | 9 | 13.4 | 19 | nC | |
| | | $I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$ | - | 8.8 | - | nC | |
| Q_{GS} | gate-source charge | $I_D = 15 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 12; Fig. 13 | 2.7 | 4.5 | 6.8 | nC | |
| $Q_{GS(th)}$ | pre-threshold gate-source charge | | 1.7 | 2.9 | 4.4 | nC | |
| $Q_{GS(th-pl)}$ | post-threshold gate-source charge | | 1 | 1.7 | 2.6 | nC | |
| Q_{GD} | gate-drain charge | | 0.6 | 2 | 4 | nC | |
| $V_{GS(pl)}$ | gate-source plateau voltage | $I_D = 15 \text{ A}; V_{DS} = 20 \text{ V};$ Fig. 12; Fig. 13 | - | 4.7 | - | V | |
| C_{iss} | input capacitance | $V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C};$ Fig. 14 | 614 | 944 | 1322 | pF | |
| C_{oss} | output capacitance | | 266 | 409 | 573 | pF | |
| C_{riss} | reverse transfer capacitance | | 13 | 44 | 97 | pF | |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 20 \text{ V}; R_L = 1.2 \text{ }^\Omega; V_{GS} = 10 \text{ V};$ $R_{G(ext)} = 5 \text{ }^\Omega$ | - | 5.1 | - | ns | |
| t_r | rise time | | - | 3.2 | - | ns | |
| $t_{d(off)}$ | turn-off delay time | | - | 8.9 | - | ns | |
| t_f | fall time | | - | 2.8 | - | ns | |
| Q_{oss} | output charge | $V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C}$ | - | 12 | - | nC | |
| Source-drain diode | | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 15 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 15 | - | 0.85 | 1 | V | |
| t_{rr} | reverse recovery time | $I_S = 15 \text{ A}; di_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 20 \text{ V};$ Fig. 16 | - | 22 | - | ns | |
| Q_r | recovered charge | | [1] | - | 15 | - | nC |
| t_a | reverse recovery rise time | | - | - | 14 | - | ns |
| t_b | reverse recovery fall time | | - | - | 8.5 | - | ns |

[1] includes capacitive recovery

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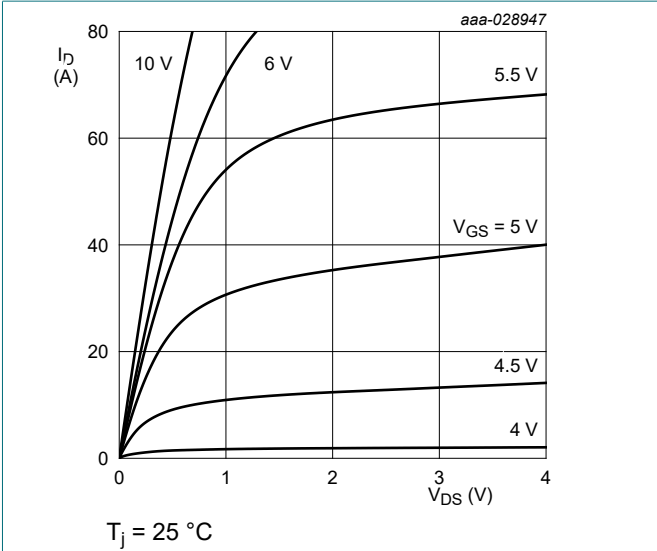


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

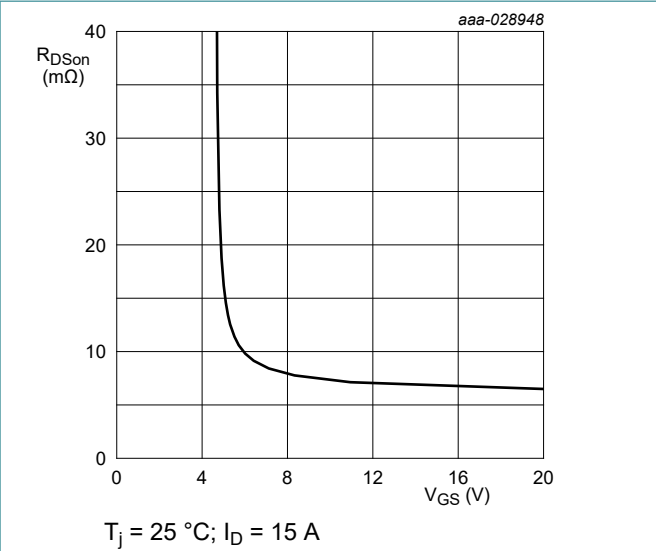


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

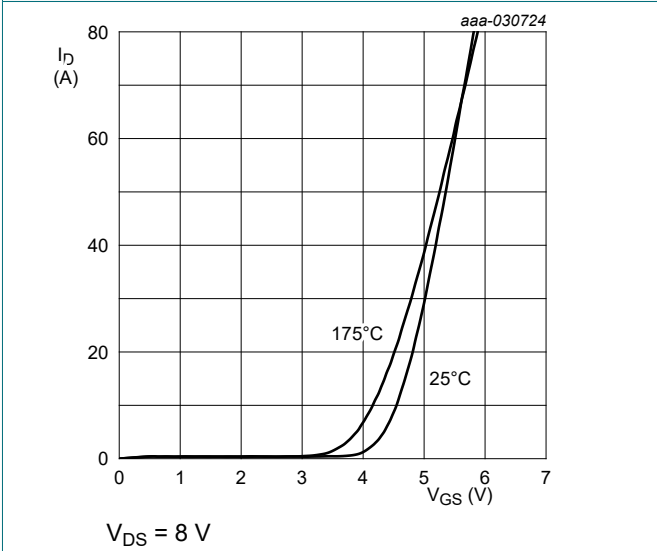


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

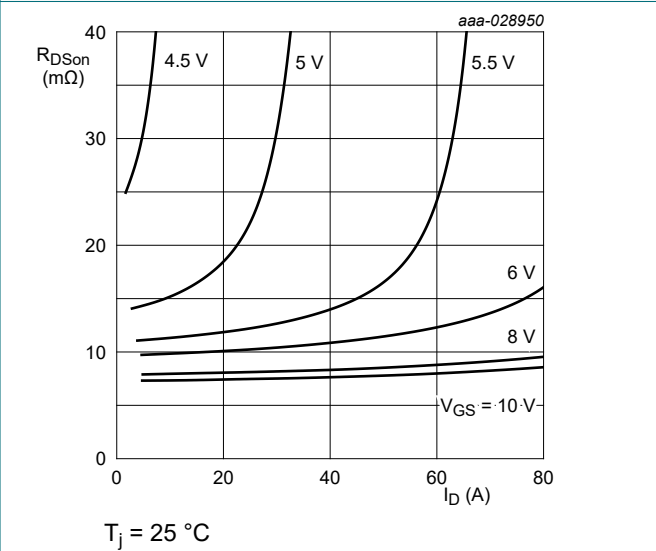
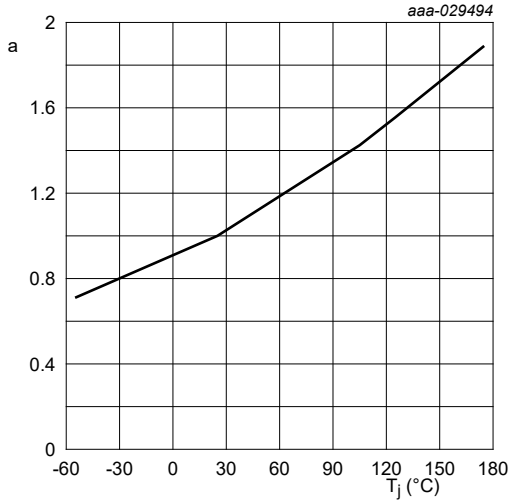
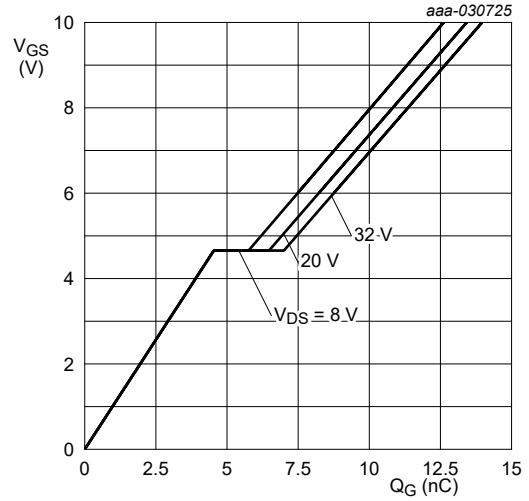


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values



$$a = \frac{R_{DSon}}{R_{DSon}(25^{\circ}\text{C})}$$

Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature



$T_j = 25^{\circ}\text{C}; I_D = 15\text{ A}$

Fig. 12. Gate-source voltage as a function of gate charge; typical values

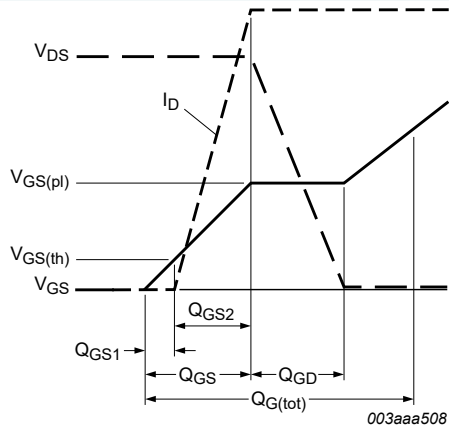
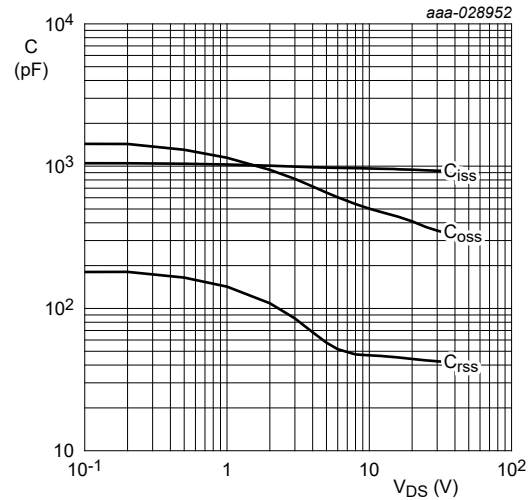
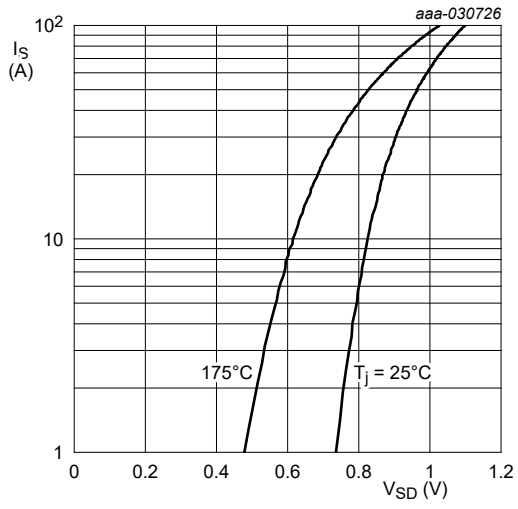


Fig. 13. Gate charge waveform definitions



$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$V_{GS} = 0\text{ V}$

Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

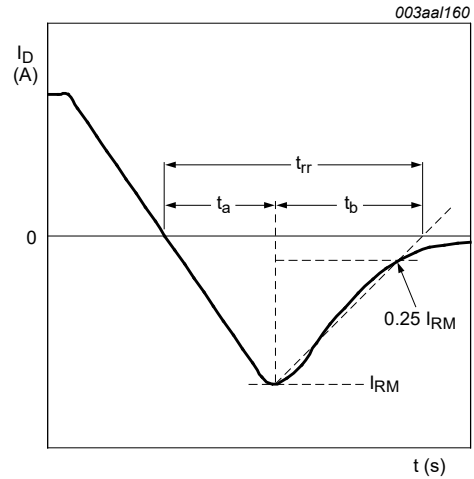


Fig. 16. Reverse recovery timing definition

11. Package outline

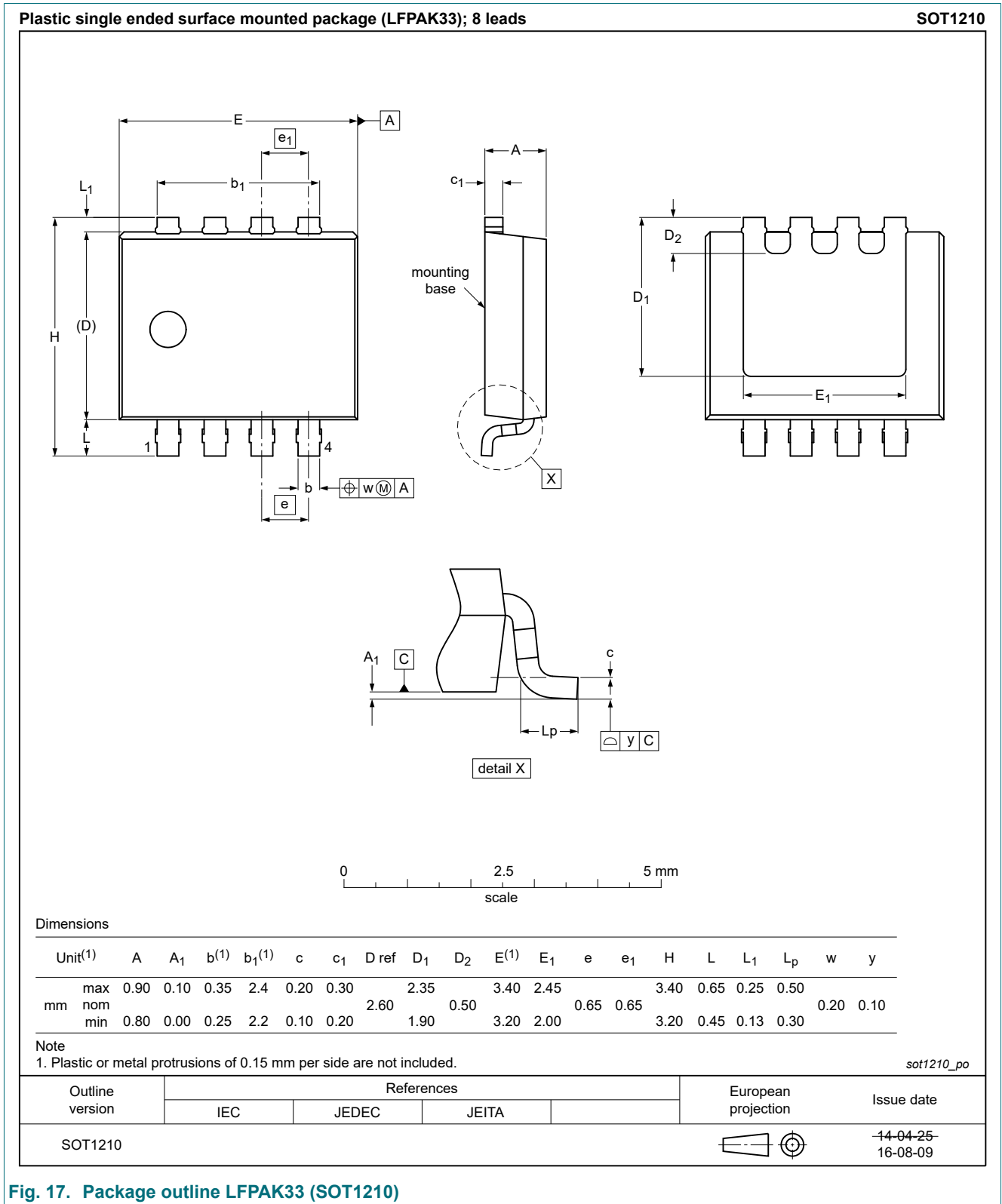


Fig. 17. Package outline LPAK33 (SOT1210)

12. Soldering

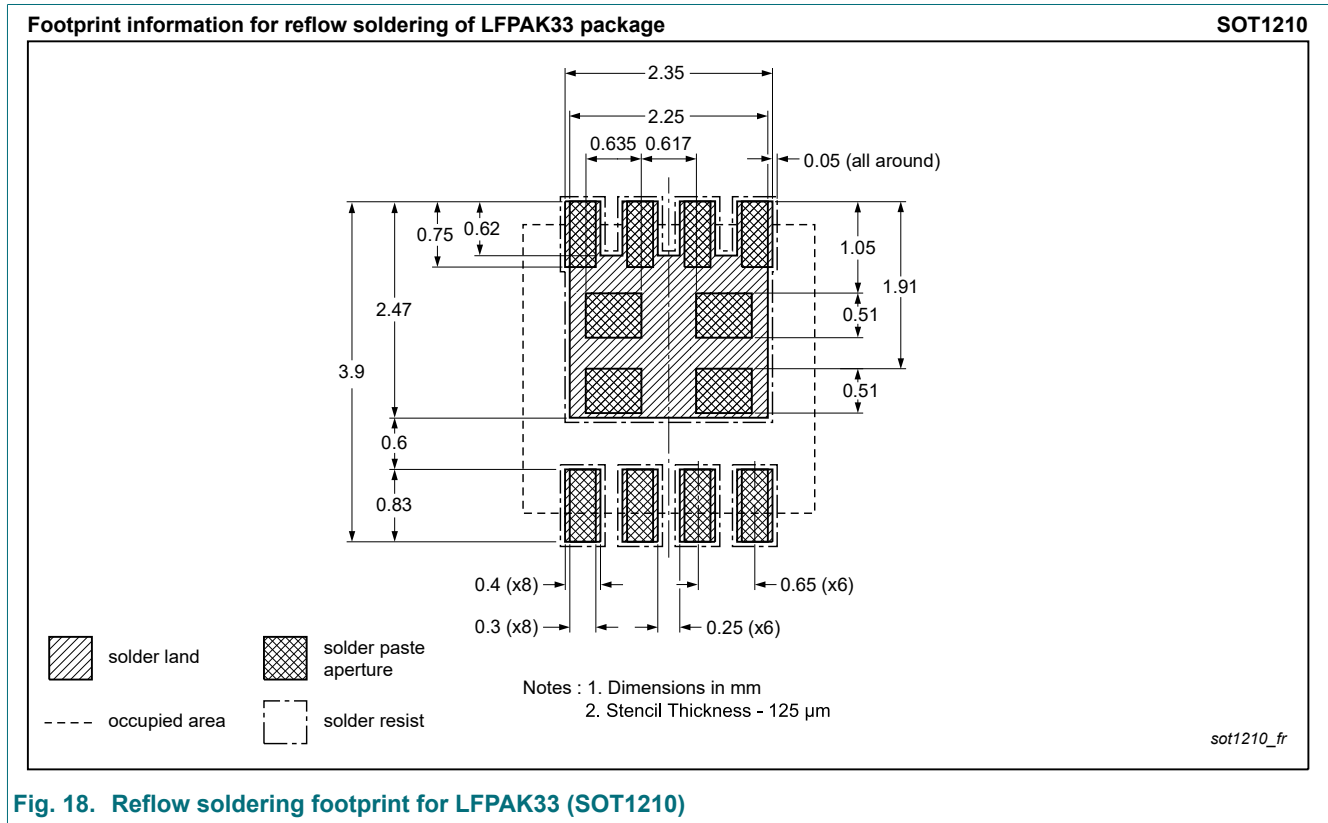


Fig. 18. Reflow soldering footprint for LPAK33 (SOT1210)

13. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
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